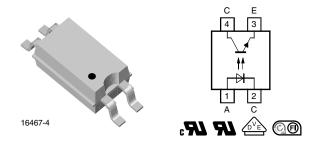
TCMT110. Series



Vishay Semiconductors

Optocoupler, Phototransistor Output, Single Channel, Half Pitch Mini-Flat Package



DESCRIPTION

The TCMT110. series consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

FEATURES

- Low profile package (half pitch)
- AC isolation test voltage 3750 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- Current transfer ratio (CTR) selected into groups
- · Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Programmable logic controllers
- Modems
- · Answering machines
- · General applications

AGENCY APPROVALS

- UL1577, file no. E76222 system code M, double protection
- cUL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5)
- FIMKO: FI EN 60950-1:2006
- BSI: BS EN60065:2002 BS EN60950-1:2006

ORDERING INFORMATION										
ТС	N] [т [1	1	0	#		SOP-4	L
	PART NUMBER 7.21 mm							•		
AGENCY CERTIFIED/	AGENCY CERTIFIED/ CTR (%)									
PACKAGE	5 mA	5 mA 10 mA 5 mA								
UL, cUL, FIMKO, BSI, VDE	50 to 600	40 to 80	63 to 125	100 to 200	160 to 320	50 to 150	100 to 300	80 to 160	130 to 260	200 to 400
SOP-4	TCMT1100	TCMT1101	TCMT1102	TCMT1103	TCMT1104	TCMT1105	TCMT1106	TCMT1107	TCMT1108	TCMT1109

Note

Available only on tape and reel.



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V_{R}	6	V				
Forward current		I _F	60	mA				
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	А				
Power dissipation		P _{diss}	100	mW				
Junction temperature		T _j	125	°C				
ОUТРUТ								
Collector emitter voltage		V _{CEO}	70	V				
Emitter collector voltage		V _{ECO}	7	V				
Collector current		I _C	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA				
Power dissipation		P _{diss}	150	mW				
Junction temperature		Tj	125	°C				
COUPLER								
AC isolation test voltage (RMS)	Related to standard climate 23/50 DIN 50014	V_{ISO}	3750	V_{RMS}				
Total power dissipation		P _{tot}	250	mW				
Operating ambient temperature range		T _{amb}	- 40 to + 100	°C				
Storage temperature range		T _{stg}	- 40 to + 125	°C				
Soldering temperature (1)		T _{sld}	260	°C				

Notes

⁽¹⁾ Wave soldering three cycles are allowed. Also refer to "Assembly Instructions" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT									
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V			
Junction capacitance	$V_R = 0$, $f = 1$ MHz	C _j		50		pF			
OUTPUT									
Collector emitter voltage	I _C = 100 μA	V _{CEO}	70			V			
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V			
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}			100	nA			
COUPLER									
Collector emitter saturation voltage	I _F = 10 mA, I _C = 1 mA	V _{CEsat}			0.3	V			
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		100		kHz			
Coupling capacitance	f = 1 MHz	C _k		0.3		pF			

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

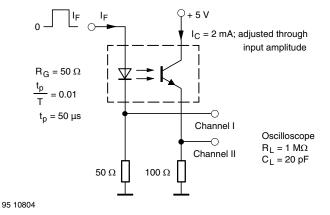


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CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
I _O /I _F	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCMT1100	CTR	50		600	%		
		TCMT1101	CTR	40		80	%		
	$V_{CF} = 5 \text{ V}, I_{F} = 10 \text{ mA}$	TCMT1102	CTR	63		125	%		
	V _{CE} = 5 V, I _F = 10 IIIA	TCMT1103	CTR	100		200	%		
		TCMT1104	CTR	160		320	%		
		TCMT1105	CTR	50		150	%		
		TCMT1106	CTR	100		300	%		
	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCMT1107	CTR	80		160	%		
		TCMT1108	CTR	130		260	%		
		TCMT1109	CTR	200		400	%		

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Delay time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _d		3		μs			
Rise time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _r		3		μs			
Fall time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _f		4.7		μs			
Storage time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _s		0.3		μs			
Turn-on time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _{on}		6		μs			
Turn-off time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω , (see figure 1)	t _{off}		5		μs			
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t _{on}		9		μs			
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t _{off}		18		μs			





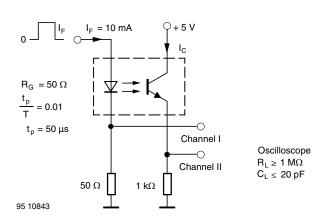


Fig. 2 - Test Circuit, Saturated Operation



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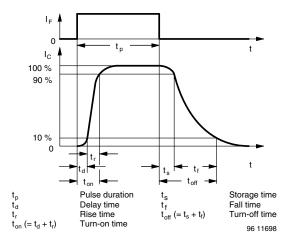


Fig. 3 - Switching Times

SAFETY AND INSULATION RATINGS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Climatic classification	IEC 68 part 1			40/110/21					
Comparative tracking index		CTI	175		399				
V _{IOTM}			6000			V			
V _{IORM}			707			V			
P _{SO}					265	mW			
I _{SI}					130	mA			
T _{SI}					150	°C			
Creepage distance			5			mm			
Clearance distance			5			mm			
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.4			mm			

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

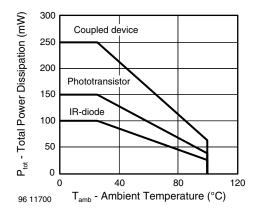


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

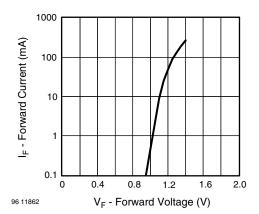


Fig. 5 - Forward Current vs. Forward Voltage

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As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



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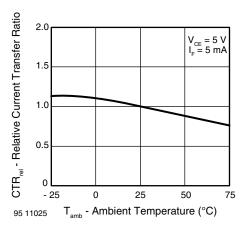


Fig. 6 - Relative Current Transfer Ratio vs.
Ambient Temperature

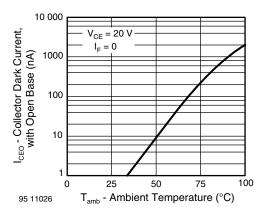


Fig. 7 - Collector Dark Current vs. Ambient Temperature

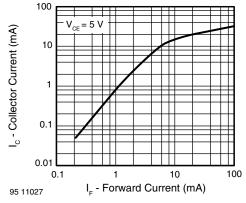


Fig. 8 - Collector Current vs. Forward Current

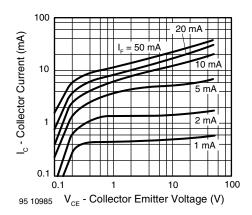


Fig. 9 - Collector Current vs. Collector Emitter Voltage

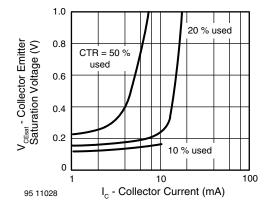


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

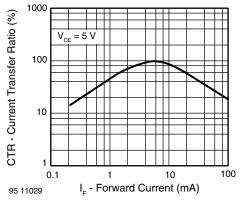


Fig. 11 - Current Transfer Ratio vs. Forward Current



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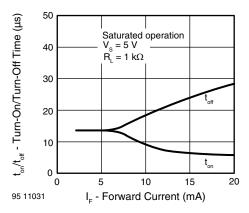


Fig. 12 - Turm-on/off Time vs. Forward Current

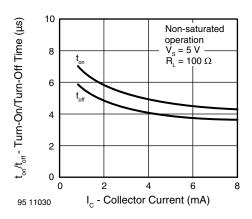
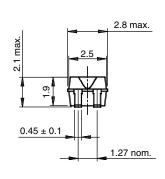
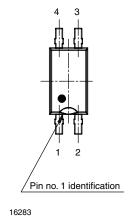


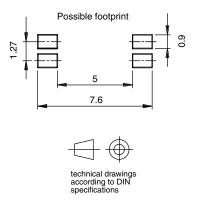
Fig. 13 - Turn-on/off Time vs. Collector Current

PACKAGE DIMENSIONS in millimeters

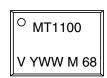




 4.4 ± 0.2 0.1 ± 0.1 + 0.10 $0.7^{+0.3}_{-0.4}$



PACKAGE MARKING (example)





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